
Influence of Ba-Sr Substitution on the Optical Properties of BaB₂O₄ Single Crystals

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Abstract

The results of studies for the optical transmission spectra, radiation hardness and the refractive indices of Ba_{1-x}Sr_xB₂O₄ (x=0.1) single crystals grown with the Czochralsky technique are presented. The investigations have shown that the substitutive Sr impurity improves the technological process of single-crystal growth, though leads simultaneously to worsening the transmittance and the radiation hardness. The assumption about the additional influence of incontrollable Na impurity on the mentioned properties of Ba_{0.9}Sr_{0.1}B₂O₄ single crystals is made.

Key words: α -BaB₂O₄ single crystals, impurities, transmission spectra, radiation hardness, refractive index

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Single crystals of both modifications of BaB₂O₄ have been considered to be promising for the optical instrument engineering. The low-temperature modification, β -BaB₂O₄ (abbreviated as BBO), belongs to the space group R3 and represents a promising material for the generation of higher harmonics of laser radiation [1], whereas the high-temperature one, α -BaB₂O₄ (or ABO; the space group R $\bar{3}c$) is used for construction of optical elements, in particular, the acoustooptic ones [2]. Nevertheless, both mentioned crystals have remained to be rather “complicated” materials from the technological viewpoint, i.e. with regards to the growth of high-quality single crystals. Among the reasons of the latter, we could mention the presence of a phase transition between the α and β phases at 925°C, which causes the appearance of strains and defects in these crystals and so worsens their optical parameters, in particular the radiation hardness.

That is why the purpose of this work is to investigate the possibility for increasing the workability of the ABO single crystals and improving their optical quality by means of particular cationic substitutions, for example, Ba with Sr. We have chosen to check the optical quality of crystals using the studies of optical transmittance, the radiation hardness and the refractive indices.

Single crystals of Ba_{1-x}Sr_xB₂O₄ compound at small x values (x < 0.13) were grown from the corresponding stoichiometric melt with the direct Czochralsky technique. In order to synthesize the Ba_{1-x}Sr_xB₂O₄ growth mixture, we used the multi-graded synthesis technique developed previously for borates [3], with the application of extra-pure materials – the BaCO₃ carbonates, the boric acid H₃BO₃, and SrCO₃. Issuing from technological considerations, we added a small (0.4 weight %) quantity of Na₂O into the melt. We found it possible to grow

successfully Ba_{1-x}Sr_xB₂O₄ single crystals of a high-grade optical quality only up to the value of $x = 0.1$. All the grown single crystals had the α -phase crystal structure. It was observed that the workability of the ABO single crystals was improved after injection of Sr impurity. In other words, a tendency to cracking the samples then lowered and the percentage of crystals having a high optical quality grew.

The studies of the transmission spectra, the optical damage threshold and the refractive indices were performed on the Ba_{0.9}Sr_{0.1}B₂O₄ ($x = 0.1$) single crystals grown by us. For the measurements of the transmittance spectra in the range of 140 – 900 nm we used the samples with the dimensions 10×10×0.2 mm³. The transmittance measurements in the range of 140 – 220 nm were performed with the spectrophotometer “McPherson VUV 2000” in the pure nitrogen atmosphere and at the room temperature, while the range of 200 – 900 nm was studied with the aid of “Specord M40” spectrophotometer. We used the technique described in the work [4] for determining the damage threshold, with the application of pulsed Nd³⁺ laser ($\tau = 6$ ns; the output radiation energy 60 mJ) and the sample of 15×8×5 mm³ dimensions. The refractive indices were

determined with the Obreimov’s index-matching technique (see, e.g., [5]) in the range of 420 – 680 nm, using the 7.8×5.1×4.1 mm³-sized sample, whose faces were oriented along the principal crystallographic axes.

The transmittance spectra in the range of 140 – 220 nm for both the pure α -BaB₂O₄ and Ba_{0.9}Sr_{0.1}B₂O₄ single crystals are shown in Figure 1 (for a comparison, the transmittance for β -BaB₂O₄ single crystal of the same thickness is given as well). As seen from the figure, the substitutive Sr impurity lowers somewhat (almost by 20%) the transmission coefficient in the range above 200 nm, i.e., above the absorption edge equal to 190 nm. However, in this just stage we cannot state for sure that the decrease in the transmittance is associated with the Sr impurity. Some uncontrollable impurities entering into the lattice of single crystal during its growth might also cause such the phenomenon. This conclusion may be arrived at after comparing the transmittance spectra of Ba_{0.9}Sr_{0.1}B₂O₄ (Figure 1, curve 3) and the pure α -BaB₂O₄ (curve 1) with the spectrum for β -BaB₂O₄ (curve 2). Notice that the growth technique for β -BaB₂O₄ single crystals also makes a presence of Na₂O in the melt quite possible. As a result, the presence of

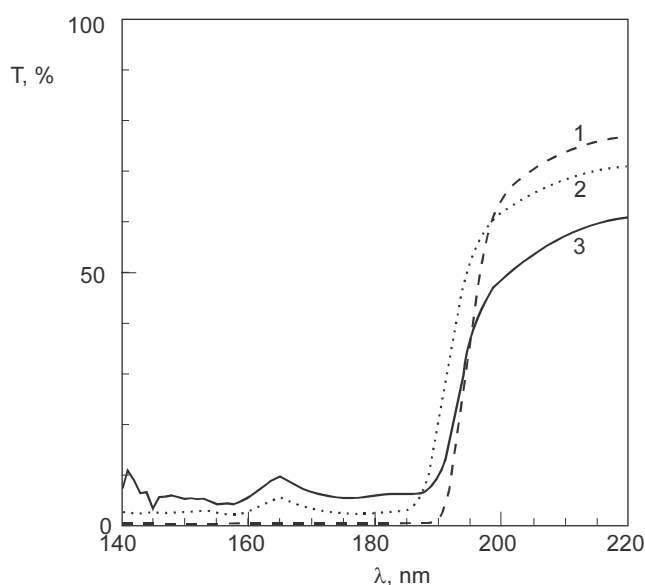


Fig. 1. The transmittance spectra of α -BaB₂O₄ (1), β -BaB₂O₄ (2) and Ba_{0.9}Sr_{0.1}B₂O₄ (3) single crystals in the range of 140 – 220 nm.

incontrollable impurity of Na^+ ions might be possible in this single crystal. It is worthwhile that we do not observe any additional absorption bands in the transmittance of all the mentioned crystals in the range of 220 – 900 nm. Here the spectral curves are parallel and practically do not differ one from another.

The results on the radiation hardness investigation for the $\text{Ba}_{0.9}\text{Sr}_{0.1}\text{B}_2\text{O}_4$ single crystal are represented in Figure 2 as the damage dimensions dependence on the focused laser beam power. When we compare the obtained results with those of the studies for $\text{CsLiB}_6\text{O}_{10}$ (CLBO), the pure ABO, BBO and the $\text{Li}_2\text{B}_4\text{O}_7$ (LTB) single crystals [4], it becomes clear that the radiation hardness of $\text{Ba}_{0.9}\text{Sr}_{0.1}\text{B}_2\text{O}_4$ has the value located between the corresponding values for the CLBO and the pure ABO crystals.

The results for the refractive indices n_o and n_e in the range of 420 – 680 nm are presented in Figure 3. As seen from the figure, $\text{Ba}_{0.9}\text{Sr}_{0.1}\text{B}_2\text{O}_4$ single crystals have sufficiently high values of optical birefringence in all the range under test. For example, we have $\Delta n \approx 0.125$ ($n_o = 1.6590$, $n_e = 1.5343$) at 533 nm. It is necessary to note that the n_o and n_e values at 533 nm somewhat differ from the refractive indices characteristic of the pure ABO ($n_o = 1.6776$, $n_e = 1.5359$ [6]). As a consequence, the birefringence has a larger value ($\Delta n = 0.142$).

Hence, one can conclude from the obtained results that the substitutive impurity of Sr, together with a possible uncontrollable impurity of Na, do affect the optical properties of the ABO single crystals. They decrease the transmittance of the latter, weaken the radiation hardness and lead to changes in the refractive indices.

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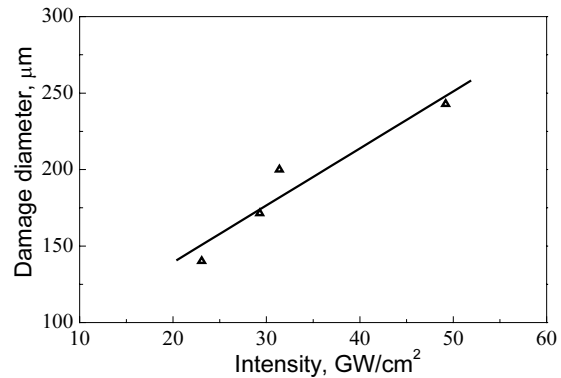


Fig. 2. Dependence of the damage diameter on the laser light intensity.

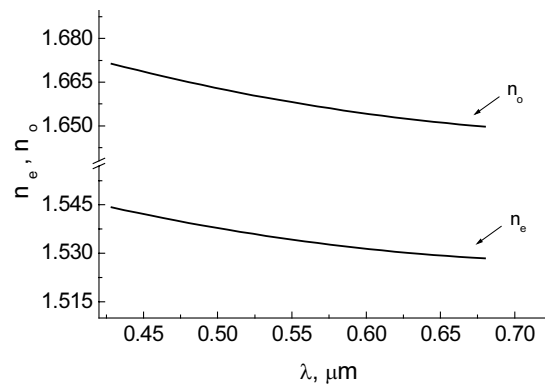


Fig. 3. Dispersion of the refractive indices of $\text{Ba}_{0.9}\text{Sr}_{0.1}\text{B}_2\text{O}_4$ single crystals at $T=20^\circ\text{C}$.

References

1. Kato K. IEEE J. Quant. Electronics **22** (1986) 1013.
2. Martynyuk-Lototska I., Mys O., Krupych O., Adamiv V., Burak Ya., Vlokh R. and Schranz W. Ferroelectrics (2004) to be published.
3. Patent 1415663 USSR MKI S 30 B 15 00. Process of obtaining of anhydrous lithium tetraborate. Burak Ya.V., Lyseiko I.T., Prostopchuk V.V., Kvasnytsia O.A., Tesliuk M.I. 1988.
4. Vlokh R., Dyachok Ya., Krupych O., Burak Ya., Martynyuk-Lototska I., Andrushchak A., Adamiv V. Ukr. J. Phys. Opt. **4** (2003) 101.
5. Romanyuk M.O. Crystal Optics, Kyjv, IZMN, 1997 (in Ukrainian).
6. S.Wu, G.Wu, J.Xie, X.Wu, Y.Zhang, X.Lin. J. Cryst. Growth **245** (2002) 84.